

HALOGEN

FREE

8-Channel, Triple 2-Channel Multiplexers

DESCRIPTION

The DG9451, and DG9453 are high precision single and dual supply CMOS analog multiplexers. DG9451 is an 8-channel multiplexer, and the DG9453 is a triple 2-channel multiplexer or triple SPDT.

Designed to operate from a ± 2.7 V to ± 12 V single supply or from a ± 2.5 V to ± 5 V dual supplies, the DG9451, and DG9453 are fully specified at ± 12 V, ± 5 V and ± 5 V. All control logic inputs have guaranteed 1.4 V high limit when operating from ± 5 V or ± 5 V supplies and 1.65 V when operating from a ± 12 V supply.

The DG9451, and DG9453 are precision multiplexers of low leakage, low charge injection, and low parasitic capacitance. They conduct equally well in both directions, offer rail to rail analog signal handling and can be used both as multiplexers as well as de-multiplexers.

The DG9451, and DG9453 operating temperature is specified from -40 $^{\circ}$ C to +85 $^{\circ}$ C and are available in 16 pin TSSOP and the ultra compact 1.8 mm x 2.6 mm miniQFN16 packages.

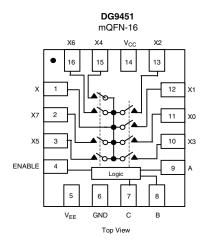
FEATURES

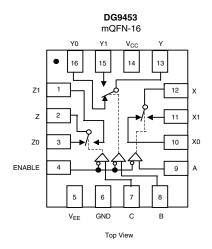
- +2.7 V to +12 V single supply operation
 ± 2.5 V to ± 5 V dual supply operation
- Fully specified at +12 V. +5 V. ± 5 V
- Low charge injection (< 0.5 pC typ.)
- High bandwidth: 270 MHz
- Low switch capacitance (C_{s(off)} 1 pF typ.)
- Good isolation and crosstalk performance (typ. -44 dB at 100 MHz)
- MiniQFN16 package (1.8 mm x 2.6 mm)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Data acquisition
- · Medical and healthcare devices
- · Control and automation equipments
- Test instruments
- Touch panels
- Consumer

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION







Device Marking: Yxx for DG9451 (miniQFN16) 4xx for DG9453 xx = Date/Lot Traceability Code

S14-2340-Rev. C, 08-Dec-14 **1** Document Number: 65020



TRUTH TA	TRUTH TABLE									
ENABLE		SELECT INPUTS		ON SWITCHES						
INPUT	С	В	Α	DG9451	DG9453					
Н	X	X	Х	All Switches Open	All Switches Open					
L	L	L	L	X to X0	X to X0, Y to Y0, Z to Z0					
L	L	L	Н	X to X1	X to X1, Y to Y0, Z to Z0					
L	L	Н	L	X to X2	X to X0, Y to Y1, Z to Z0					
L	L	Н	Н	X to X3	X to X1, Y to Y1, Z to Z0					
L	Н	L	L	X to X4	X to X0, Y to Y0, Z to Z1					
L	Н	L	Н	X to X5	X to X1, Y to Y0, Z to Z1					
L	Н	Н	L	X to X6	X to X0, Y to Y1, Z to Z1					
L	Н	Н	Н	X to X7	X to X1, Y to Y1, Z to Z1					

ORDERING INFORMATION								
TEMP. RANGE PACKAGE PART NUMBER								
DG9451, DG9453								
40 °C to 1105 °C 8	16 Din miniOFN	DG9451EN-T1-E4						
-40 °C to +125 °C ^a	16-Pin miniQFN	DG9453EN-T1-E4						

Note

a. -40 °C to +85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)								
PARAMETER		LIMIT	UNIT					
V+ to V-		14						
GND to V-		7	V					
Digital Inputs ^a , V _S , V _D		(V-) -0.3 to (V+) +0.3 or 30 mA, whichever occurs first						
Continuous Current (Any Terminal)		30	A					
Peak Current, S or D (Pulsed 1 ms, 10	0 % duty cycle)	100	- mA					
Storage Temperature		-65 to +150	°C					
Power Dissipation ^b 16-Pin miniQFN ^{c, d}		525	mW					
Thermal Resistance b 16-Pin miniQFN d		152	°C/W					
Latch-up (per JESD78)	•	> 300	mA					

Notes

- a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



	TEST CONDITIONS					-40 °C to +125 °C		-40 °C to +85 °C		
PARAMETER	SYMBOL	UNLESS OTHERWIS V _{CC} = +5 V, V _{EE}		TEMP.b	TYP. °	MIN. d	MAX. d	MIN. d	MAX. d	UNI
		V _{IN(A, B, C AND ENABLE)} =	1.4 V, 0.3 V ^a			1011141	1011 (54)		IVII D CI	
Analog Switch										
Analog Signal Range e	V _{ANALOG}			Full	-	-5	5	-5	5	V
On-Resistance	R _{ON}	$I_S = 1 \text{ mA}, V_D = -3 $	/ 0 \/ ±3 \/	Room	66	-	100	-	100	
On-Hesistance	I ION	is = 1 ma, v _D = -5 v	Full	-	-	125	-	118		
On-Resistance Match	ΔR_{ON}	$I_{S} = 1 \text{ mA, } V_{D} =$	- + 3 V	Room	3	-	6	-	6	Ω
On-Hesistance Materi	ΔI ION	is – i iliz, vb -	Full	-	-	10	-	8	52	
On-Resistance Flatness	R _{FLATNES}	$I_S = 1 \text{ mA}, V_D = -3 $	Room	10.2	-	16	-	16		
On-nesistance matriess	S	IS = 1 IIIA, VD = -3 V	7, 0 V, +3 V	Full	-	-	20	-	18	
	ı			Room	± 0.02	-1	1	-1	1	
Switch Off	I _{S(off)}	V+ = 5.5 V, V- =		Full	-	-50	50	-5	5	
Leakage Current		$V_D = \pm 4.5 \text{ V}, V_S =$: ∓ 4.5 V	Room	± 0.02	-1	1	-1	1	- /
	I _{D(off)}			Full	-	-50	50	-5	5	n/
Channel On		V+ = 5.5 V, V- =	: -5.5 V,	Room	± 0.02	-1	1	-1	1	
Leakage Current	I _{D(on)}	$V_S = V_D = \pm 4$	4.5 V	Full	-	-50	50	-5	5	
Digital Control					I.	I.	l	I.	I.	
V _{IN(A. B. C and ENABLE)} Low	V _{IL}			Full	-	-	0.3	-	0.3	
V _{IN(A, B, C and ENABLE)} High	V _{IH}			Full	_	1.4	-	1.4	-	V
Input Current, V _{IN} Low	IIL	V _{IN(A, B, C and ENABLE)} und	der test = 0.3 V	Full	0.01	-1	1	-1	1	
Input Current, V _{IN} High	I _{IH}	V _{IN(A, B, C and ENABLE)} und	Full	0.01	-1	1	-1	1	μA	
Input Capacitance e	C _{IN}	f = 1 MHz		Room	3.4	-	_	_	-	pl
Dynamic Characteristics	Olly	1 - 1 1411 12	_	1100111	0.1					Ρ.
Dynamic Gnaractoricaes				Room	66	_	180	_	180	
Transition Time	t _{TRANS}			Full	-	_	218	_	207	1
		$R_1 = 300 \Omega, C_1 = 35 pF$		Room	152	_	250	_	250	1
Enable Turn-On Time	t _{ON}			Full	-	_	295	_	282	
		$R_L = 300 \Omega$, C_L , see figure 1,	•	Room	60	_	125	_	125	ns
Enable Turn-Off Time	t _{OFF}	occ ligate 1,	2, 0	Full	00	-	136	_	131	
Dunali Dafava Malia		-			32	_	-	_	-	
Break-Before-Make Time Delay	t_D			Room Full	32	-	13	_	13	
Time Delay			f = 100 kHz			-	-	-	13	
O# la alation 6	OIRR			Room	< -90	-		-	-	
Off Isolation e			f = 10 MHz	Room	-65	-	-	-	-	
		$R_L = 50 \Omega, C_L = 15 pF$	f = 100 MHz	Room	-44	-	-	-	-	dE
Channel-to-Channel			f = 100 kHz	Room	< -90	-	-	-	-	
Crosstalk ^e	X_{TALK}		f = 10 MHz	Room	-74	-	-	-	-	
			f = 100 MHz	Room	-44	-	-	-	-	
Bandwith, 3 dB	BW	$R_L = 50 \Omega$	DG9451	Room	270	-	-	-	-	MH
-		_	DG9453	Room	525	-	-	-	-	
Charge Injection e	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega,$		Room	0.20	-	-	-	-	p(
Source Off Capacitance e	C _{S(off)}	f = 1 MHz	DG9451	Room	1	-	-	-	-	
	- 0(011)		DG9453	Room	1	-	-	-	-	
Drain Off Capacitance e	$C_{D(off)}$	f = 1 MHz	DG9451	Room	10	-	-	-	-	рŀ
	OD(011)		DG9453	Room	3	-	-	-	-	ρ.
Channel On Capacitance e	C _{D(on)}	f = 1 MHz	DG9451	Room	16	-	-	-	-	
	OD(011)		DG9453	Room	8	-	-	-	-	
Total Harmonic Distortion e	THD	Signal = 1 V		Room	0.01	_	-	_	_	%
		20 Hz to 20 kHz, F	rΓ = ρηη 73					<u> </u>		
Power Supplies				Г.	0.05	ı		ı		
Power Supply Current	I+			Room	0.05	-	1	-	1	
N. 1. 2				Full	-	-	10	-	10	
Negative Supply Current	l-	$V_{CC} = +5 \text{ V}, V_{EE}$	= -5 V	Room Full	-0.05	-1	-	-1	-	μΑ
game cappi, canoni	•	V _{IN(A, B, C and ENABLE)}	V _{IN(A, B, C and ENABLE)} = 0 V or 5 V		_	-10	-	-10	-	μ,
Ground Current	I _{GND}			Room	-0.05	-1	=	-1	-	
GIOGIA OUITOIL	GND			Full	-	-10	-	-10	-	Ì



	TEST CONDITIONS					-40 °C to	+125 °C	-40 °C to	o +85 °C	
PARAMETER	SYMBOL	UNLESS OTHERWISE SPECIFIED		TEMP.b	TYP. a					UNI
		$V_{CC} = +5 \text{ V}, V_{EE} = V_{IN(A, B, C \text{ AND ENABLE})} = 1.4$	U V 1 V O 3 V a			MIN. d	MAX. d	MIN. d	MAX. d	
Analog Switch		*IN(A, B, C AND ENABLE) = 11	. •, •.• •							
Analog Signal Range ^e	V _{ANALOG}			Full	l _	0	5	0	5	V
Analog Olgital Harige	VANALOG			Room	105	-	165	-	165	•
On-Resistance	R _{ON}	$I_S = 1 \text{ mA}, V_D = 0 \text{ V}, -1 \text{ mA}$	+3.5 V	Full	-	_	205	_	194	
				Room	3.2	_	8		8	
On-Resistance Match	ΔR_{ON}	$I_S = 1 \text{ mA}, V_D = +3$.5 V	Full			13		10	Ω
				_	-		-	-		
On-Resistance Flatness	R _{FLATNESS}	$I_S = 1 \text{ mA}, V_D = 0 \text{ V},$	+3 V	Room	17	-	26	-	26	
				Full	-	-	30	-	28	
	I _{S(off)}			Room	± 0.02	-1	1	-1	1 -	
Switch Off		$V_{+} = +5.5 \text{ V}, V_{-} = V_{D} = 1 \text{ V}/4.5 \text{ V}, V_{S} = 4.$		Full	-	-50	50	-5	5	
Leakage Current	I _{D(off)}	$V_D = 1 \text{ V/4.5 V}, V_S = 4.$.5 V/ I V	Room	± 0.02	-1	1	-1	1	nA
	- \/			Full	-	-50	50	-5	5	
Channel On	I _{D(on)}	V+ = +5.5 V, V- =		Room	± 0.02	-1	1	-1	1	
Leakage Current	D(OII)	$V_D = V_S = 1 \text{ V}/4.5$	Full	-	-50	50	-5	5		
Digital Control				ı	1		1			
V _{IN(A, B, C and ENABLE)} Low	V_{IL}			Full	-	-	0.3	-	0.3	V
$V_{IN(A,\;B,\;C\;and\;ENABLE)}$ High	V_{IH}			Full	-	1.4	-	1.4		·
Input Current, V _{IN} Low	ΙL	V _{IN(A, B, C and ENABLE)} under	test = 0.3 V	Full	0.01	-1	1	-1	1	μA
Input Current, V _{IN} High	I _H	V _{IN(A, B, C and ENABLE)} under	Full	0.01	-1	1	-1	1	μΑ	
Dynamic Characteristics	s									
Turn siting Time		t _{TRANS}		Room	79	-	205	-	205	
Transition Time	t _{TRANS}			Full	-	-	295	-	285	
				Room	220	-	335	-	335	
Enable Turn-On Time	t _{ON}	B ₁ = 300 O C ₁ = 3	5 pF	Full	-	-	403	-	393	-
	1	$R_L = 300 \Omega, C_L = 35 pF$ See Figure 1, 2, 3		Room	93	-	150	-	150	ns -
Enable Turn-Off Time	t _{OFF}		Full	_	_	173	_	163		
Break-Before-Make				Room	36	_	-	_	-	
Time Delay	t_D			Full	-	_	20	_	20	
Charge Injection e	Q	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L$	_ 1 nF	Full	0.81	_	-	_	-	рС
Off Isolation e	OIRR	vg - 0 v, rig - 0 s2, OL	1 111	Room	< -90		_		-	ρυ
Channel-to-Channel	OINN	$R_L = 50 \Omega, C_L = 15$	5 pF	1100111	\ -3U				_	dB
Crosstalk ^e	X _{TALK}	f = 100 kHz		Room	< -90	ı	-	1	-	GD
Dynamic Characteristics	S									
Course Off Consoitenes 6		f 1 MI I-	DG9451	Room	1	-	-	-	-	
Source Off Capacitance e	C _{S(off)}	f = 1 MHz	DG9453	Room	1	-	-	-	-	
D : 0" 0 :: 0			DG9451	Room	11	-	-	-	-	_
Drain Off Capacitance e	$C_{D(off)}$	f = 1 MHz	DG9453	Room	3	-	-	-	-	pF
urain Uπ Capacitance e			DG9451	Room	17	-	-	-	-	
·	_	$C_{D(on)}$ $f = 1 \text{ MHz}$ $DG9453$		Room	9	-	_	_	_	-
Channel On Capacitance ^e	C _{D(on)}	1 = 1 1011 12	DG9453	HOOIII			<u> </u>			
·	C _{D(on)}	1 – 1 101112	DG9453	HOOIII						<u> </u>
Channel On Capacitance e Power Supplies		1 – 1 171112	DG9453	Room	0.05	-	1	-	1	
Channel On Capacitance e	C _{D(on)}	I – I IVII IZ	DG9453			-		-		
Channel On Capacitance e Power Supplies Power Supply Current	I+			Room	0.05		1		1	
Channel On Capacitance e Power Supplies		V _{IN(A, B, C and ENABLE)} = 0		Room Full	0.05	-	1	-	1	μА
Channel On Capacitance e Power Supplies Power Supply Current	I+			Room Full Room	0.05	- -1	1 10 -	- -1	1 10 -	μΑ



		TEST CONDITION		<u>-</u>		-40 °C to	+125 °C	-40 °C to	+85 °C	
PARAMETER	SYMBOL	UNLESS OTHERWISE SPECIFII		TEMP.b	TYP. °				MAX.	UNI
		$V_{CC} = +12 \text{ V}, V_{EE}$ V = 1.6 V, 0.5 V				MAX. d	MIN. d	MIN. d	D	
Analog Switch		V = 1.0 V, 0.5	•		L					
Analog Signal Range e	V _{ANALOG}			Full	Ι -	0	12	0	12	V
Analog olgilai Harige	VANALOG			Room	68	-	105	-	105	,
On-Resistance	R _{ON}	$I_S = 1 \text{ mA}, V_D = 0.7 \text{ V},$	6 V, 11.3 V	Full	-	_	143	-	137	
				Room	4	_	7	_	7	
On-Resistance Match	ΔR_{ON}	$I_{S} = 1 \text{ mA}, V_{D} = +$	0.7 V	Full	-	_	10	-	8	Ω
				Room	32	_	45	-	45	
On-Resistance Flatness	R _{FLATNESS}	$I_S = 1 \text{ mA}, V_D = 0.7 \text{ V}$	′, +11.3 V	Full	-	_	49	-	47	
				Room	± 0.02	-1	1	-1	1	
Switch Off	I _{S(off)}	V+ = +12 V, V- =	- 0 V	Full	-	-50	50	-5	5	
Leakage Current		$V_D = 1 \text{ V/11 V}, V_S =$		Room	± 0.02	-1	1	-1	1	
	I _{D(off)}	, , ,		Full	-	-50	50	-5	5	nA
Channel On		V+ = +12 V, V- =	- 0 V	Room	± 0.02	-1	1	-1	1	
Leakage Current	I _{D(on)}	$V_D = V_S = 1 \text{ V/1}$		Full	-	-50	50	-5	5	
Digital Control					<u> </u>					
V _{IN(A, B, C and ENABLE)} Low	V _{IL}			Full	-	-	0.5	-	0.5	
V _{IN(A, B, C and ENABLE)} High	V _{IH}			Full	-	1.6	-	1.6	-	V
Input Current, V _{IN} Low	l _l	V _{IN(A, B, C and ENABLE)} unde	er test = 0.5 V	Full	0.01	-1	1	-1	1	
Input Current, V _{IN} High	I _H	V _{IN(A, B, C and ENABLE)} unde	Full	0.01	-1	1	-1	1	μΑ	
Dynamic Characteristics		inv(r, b, o and brother)			<u> </u>	l				
-				Room	55	_	135	- 1	135	
Transition Time	t _{TRANS}			Full	-	-	166	-	155	
Facility Town On The				Room	106	-	185	-	185	
Enable Turn-On Time	t _{ON}	$R_1 = 300 \Omega, C_1 =$	35 pF	Full	-	-	219	-	205	
Facility To a Office	t _{OFF}	see figure 1, 2, 3		Room	65	-	130	-	130	ns
Enable Turn-Off Time				Full	-	-	144	-	137	
Break-Before-Make					30	-	-	-	-	
Time Delay	t _D			Full	-	-	12	-	12	
Charge Injection e	Q	$V_{a} = 0 \text{ V}, R_{a} = 0 \Omega, C$	C _L = 1 nF	Room	0.79	-	-	-	-	рС
Dynamic Characteristics	1					,				
Off Isolation e	OIRR	D 5000	15 5	Room	< -90	-	-	-	-	
Channel-to-Channel Crosstalk ^e	X _{TALK}	$R_L = 50 \Omega, C_L = 7$ f = 100 kHz		Room	< -90	-	-	-	-	dB
Course Off Conseitance 6	_	f 1 MI I-	DG9451	Room	1	-	-	-	-	
Source Off Capacitance e	C _{S(off)}	f = 1 MHz	DG9453	Room	1	-	-	-	-	
Drain Off Canasitanas a	_	f _ 1 MI I~	DG9451	Room	9	-	-	-	-	~F
Drain Off Capacitance e	$C_{D(off)}$	f = 1 MHz	DG9453	Room	3	-	-	-	-	pF
Channel On Capacitance e	C-	f = 1 MHz	DG9451	Room	15	-	-	-	-	
•	C _{D(on)}	I = I IVIMZ	DG9453	Room	8	-	-	-	-	
Power Supplies										
Power Supply Current	I+			Room	0.05	-	1	-	1	
. Stroi Guppiy Guiront	i.t.			Full	-		10	-	10	
Negative Supply Current	I-	V _{IN(A, B, C and ENABLE)} = 0	N V or 12 V	Room	-0.05	-1	-	-1	-	μA
racgative oupply ourient	1=	IN(A, B, C and ENABLE) = 1	0 V OI 12 V	Full	-	-10	-	-10	-	μΛ
Ground Current	love			Room	-0.05	-1	-	-1	-	
Ground Ourient	I _{GND}		Full	-	-10	-	-10	-		

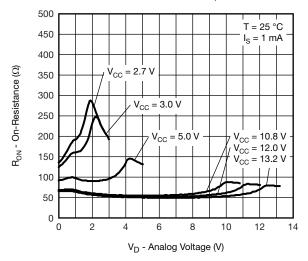
Notes

- a. V_{IN} = input voltage to perform proper function.
- b. Room -25 °C, Full = as determined by the operating temperature suffix.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- e. Guaranteed by design, not subject to production test.

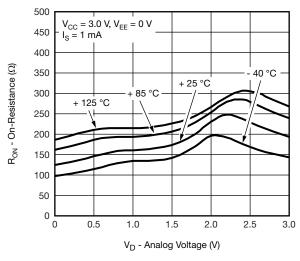
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



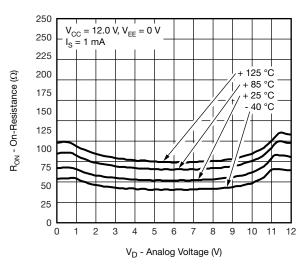
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



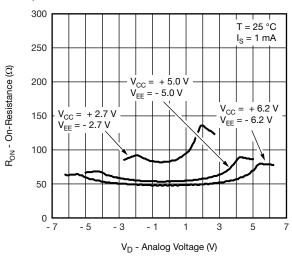
On-Resistance vs. V_D and Signal Supply Voltage



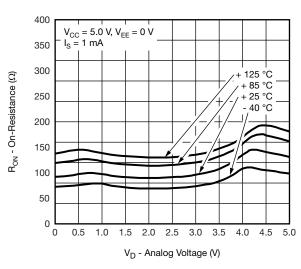
On-Resistance vs. Analog Voltage and Temperature



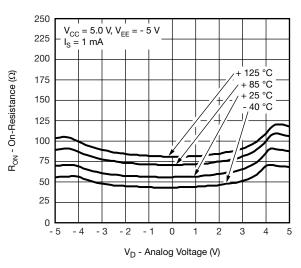
On-Resistance vs. Analog Voltage and Temperature



On-Resistance vs. Analog Voltage and Temperature



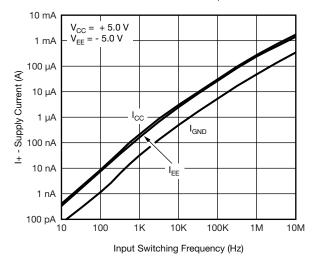
On-Resistance vs. Analog Voltage and Temperature



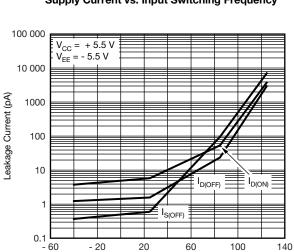
On-Resistance vs. Analog Voltage and Temperature



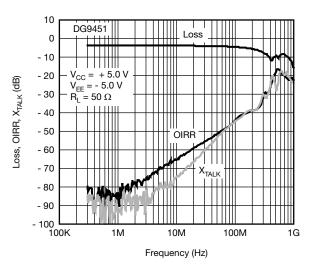
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



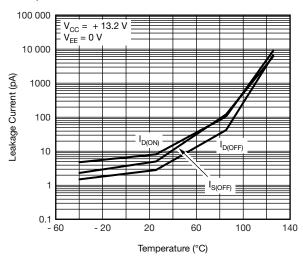
Supply Current vs. Input Switching Frequency



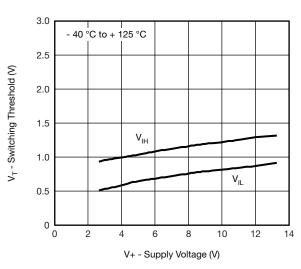
Temperature (°C) Leakage Current vs. Temperature



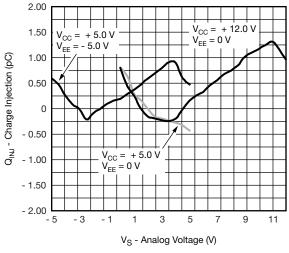
DG9451 Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



Leakage Current vs. Temperature



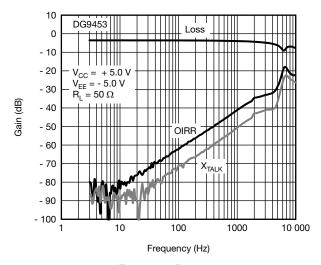
Switching Threshold vs. Supply Voltage



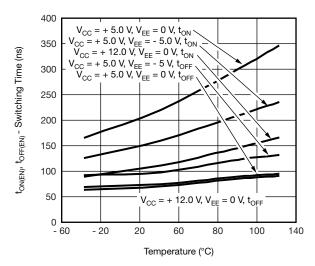
DG9451 Charge Injection vs. Analog Voltage



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

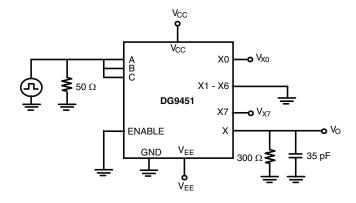


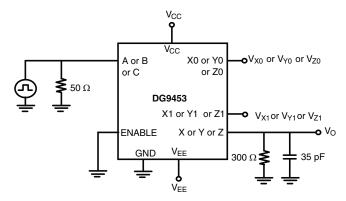
Frequency Response



Switching Time vs. Temperature

TEST CIRCUITS





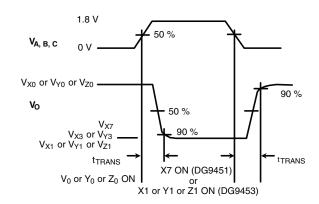


Fig. 1 - Transition Time



TEST CIRCUITS

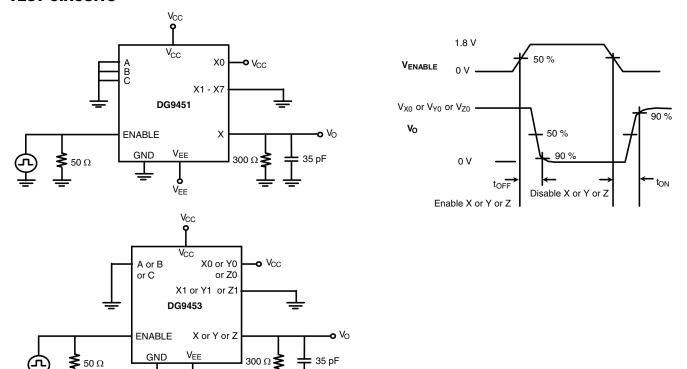


Fig. 2 - Enable Switching Time

 V_{EE}

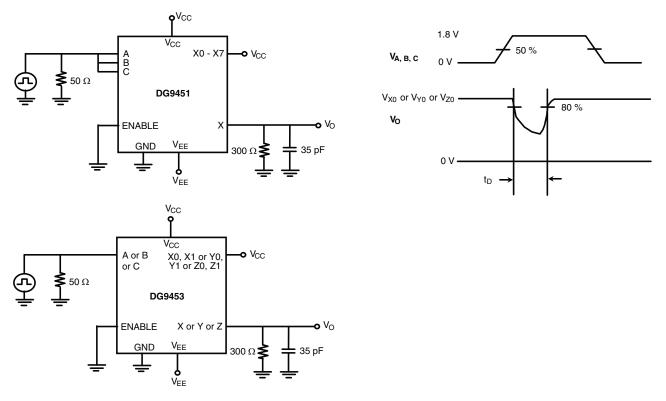


Fig. 3 - Break-Before-Make



TEST CIRCUITS

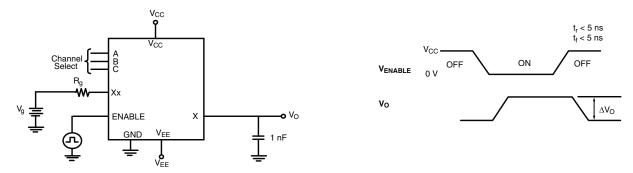
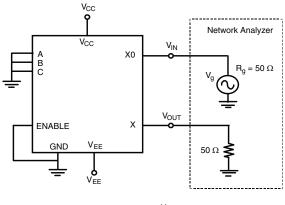


Fig. 4 - Charge Injection



Insertion Loss = 20 log

Network Analyzer VIN X0 $R_q = 50 \Omega$ VOLIT V_{CC}o **ENABLE** Х V_{EE} V_{EE} Off Isolation = 20 log $\frac{V_{OUT}}{V_{IN}}$

Fig. 5 - Insertion Loss

Fig. 7 - Off Isolation

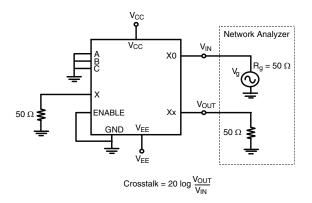


Fig. 6 - Crosstalk

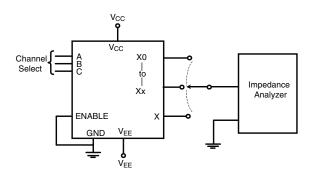
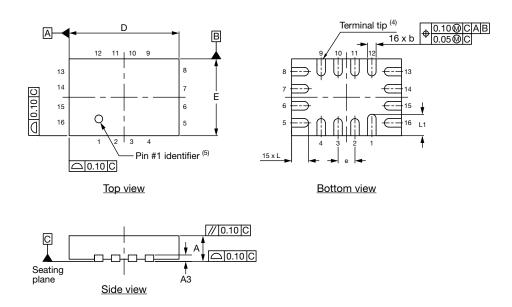


Fig. 8 - Source, Drain Capacitance

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Thin miniQFN16 Case Outline



DIMENSIONS		MILLIMETERS (1)		INCHES					
DIMENSIONS	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.			
А	0.50	0.55	0.60	0.020	0.022	0.024			
A1	0	-	0.05	0	-	0.002			
A3		0.15 ref.			0.006 ref.				
b	0.15	0.20	0.25	0.006	0.008	0.010			
D	2.50	2.60	2.70	0.098	0.102	0.106			
е		0.40 BSC		0.016 BSC					
E	1.70	1.80	1.90	0.067	0.071	0.075			
L	0.35	0.40	0.45	0.014	0.016	0.018			
L1	0.45	0.50	0.55	0.018	0.020	0.022			
N (3)		16			16				
Nd ⁽³⁾		4			4				
Ne ⁽³⁾		4		4					

Notes

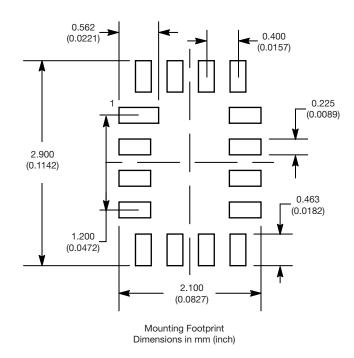
- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

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DWG: 6023



RECOMMENDED MINIMUM PADS FOR MINI QFN 16L





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